TOSHIBA Photocoupler GaAs IRed & Photo-Transistor

# **TLP531, TLP532**

Programmable Controllers AC / DC-Input Module Solid State Relay

The TOSHIBA TLP531 and TLP532 consist of a photo-transistor optically coupled to a gallium arsenide infrared emitting diode in a six lead plastic DIP. TLP532 hss no-base internal connection for high-EMI environments.

Collector-emitter voltage : 55 V (min)
 Current transfer ratio : 50% (min)
 Rank GB : 100% (min)

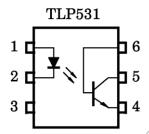
Isolation voltage : 2500 V<sub>rms</sub> (min)

• UL recognized : UL1577, file no. E67349

c-UL approved : CSA Component Acceptance Service

No. 5A, File No.E67349

### Pin Configurations (top view)



1: ANODE

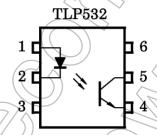
2: CATHODE

3:N.C.

4 : EMITTER

5 : COLLECTOR

6: BASE



1 : ANODE

2: CATHODE

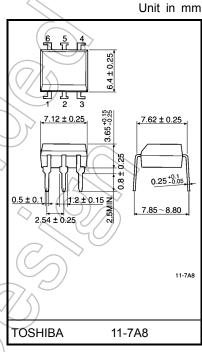
3 : N.C.

4 : EMITTER

5 : COLLECTOR

1

6<sub>∼</sub>: N.C.



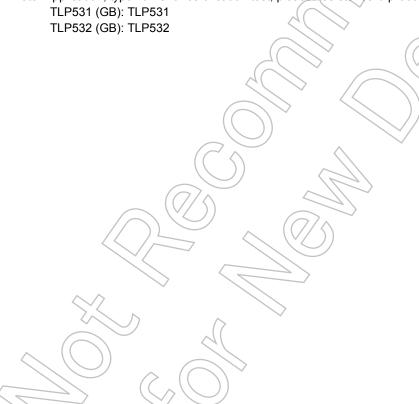
Weight: 0.4g (typ.)

#### **Current Transfer Ratio**

	Current Transfer	Ratio (%) (I <sub>C</sub> /I <sub>F</sub> )	
Classification (Note 1)	I <sub>F</sub> = 5 mA, V <sub>CE</sub> :	= 5 V, Ta = 25°C	Marking Of Classification
, ,	Min	Max	
Blank	50	600	Blank, Y <sup>■</sup> , YE, G, G <sup>■</sup> , GR, B, BL, GB
Rank Y	50	150	YE, Y■
Rank GR	100	300	GR, G, G <sup>■</sup>
Rank BL	200	600	BL, B
Rank GB	100	600	GB, G, G <sup>■</sup> , GR, B, BL
Rank YH	75	150	Y ( ) >
Rank GRL	100	200	G
Rank GRH	150	300	G* (1)
Rank BLL	200	400	В

Note 1: EX, Rank GB: TLP531 (GB), TLP532(GB)

Note: Application, type name for certification test, please use standard product type name, i, e



#### Absolute Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit
	Forward current	lF	70	mA
	Forward current derating (Ta ≥ 50°C)	ΔI <sub>F</sub> /°C	-0.93	mA/°C
	Peak forward current (100 µs pulse, 100 pps)	IFP	1	Á
LED	Reverse voltage	VR	5	V
_	Diode power dissipation		50	mW
	Diode power dissipation derating (Ta ≥50°C)	ΔP <sub>D</sub> /°C	-0.67	mW/°C
	Junction temperature	Tj	125	(°c)
	Collector-emitter voltage	VCEO	55	V
	Collector-base voltage (TLP531)	V <sub>CBO</sub>	80	) V
	Emitter-collector voltage		7	V
ctor	Emitter-base voltage (TLP531)	V <sub>EBO</sub>	7	V
Detector	Collector current	Ic	50	mA
	Power dissipation	Pc	150	mW
	Power dissipation derating (Ta ≥ 25°C)	ΔP <sub>C</sub> /°C	-1.5	mW/°C
	Junction temperature	Ţ <sub>i</sub>	125	(°C/
Storage	e temperature range	T <sub>stg</sub>	-55 to 125	°C ~
Operat	ing temperature range	Topr	-55 to 100 (	//°¢
Lead soldering temperature (10 s)		T <sub>sol</sub>	260	c
Total package power dissipation		PT	250	mW
Total package power dissipation derating (Ta ≥ 25°C)		ΔP <sub>T</sub> /°C	-2.5	mW/°C
Isolatio	on voltage (AC, 1minute, R.H.≤ 60%) (Note 1)	BVs	2500	V <sub>rms</sub>

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: This device is considered as a two-terminal device: All pins on the LED side are shorted together, and all pin on the photodetector side are shorted together.

#### **Recommends Operating Conditions**

Characteristic	Symbol	Min	Тур.	Max	Unit
Supply voltage	Vcc	_	5	24	V
Forward current	lF	_	16	25	mA
Collector current	IC	_	1	10	mA
Operating temperature	T <sub>opr</sub>	-25	_	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.



### Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	VF	I <sub>F</sub> = 10 mA	1.0	1.15	1.3	V
LED	Reverse current	IR	V <sub>R</sub> = 5 V	_	_	10	μΑ
	Capacitance	CT	V = 0 V, f = 1 MHz	V	30	_	pF
	Collector-emitter breakdown voltage	V(BR)CEO	IC = 0.5 mA	55	1/2	ı	V
	Emitter-collector breakdown voltage	V <sub>(BR)ECO</sub>	I <sub>E</sub> = 0.1 mA	)		1	V
	Collector-base breakdown voltage (TLP531)	V <sub>(BR)</sub> CBO	I <sub>C</sub> = 0.1 mA	80	-	١	V
ōř	Emitter-base breakdown voltage (TLP531)	V(BR)EBO	IE = 0.1 mA	7	- (	_	V
Detector	Collector dark current (TLP531)	lone	V <sub>CE</sub> = 24 V	_	10	100	nA
۵	Collector dark current (TLP531)	ICEO	V <sub>CE</sub> = 24 V, Ta = 85°C	- (	2	50	
	Collector cut-off current (TLP531)	ICER	V <sub>CE</sub> = 24 V, Ta = 85°C R <sub>BE</sub> = 1 MΩ	1	0.5	10	μΑ
	Collector cut-off current (TLP531)	I <sub>CBO</sub>	V <sub>CB</sub> = 10 V	-//	0.1	_	nA
	DC current gain (TLP531)	hFE	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 0.5 mA		400	_	_
	Capacitance (collector to emitter)	C <sub>CE</sub>	V = 0 V, f = 1 MHz		10	_	pF

# Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	ì	MIn	Тур.	Max	Unit
Current transfer ratio	IC/IF	IF = 5 mA, VCE = 5 V		50	_	600	%
Current transfer ratio	IOII		Rank GB	100	_	600	/0
Saturated CTP		IF = 1 mA, V <sub>OE</sub> = 0.4 V		1	60	1	%
Saturated CTR	IC/IF(sat)		Rank GB	30	_	1	70
		IC = 2.4 mA, IF = 8 mA		-	_	0.4	
Collector-emitter saturation voltage	VCE(sat)	IC = 0.2 mA, IF = 1 mA		_	0.2	_	V
$\rightarrow$	'		Rank GB	1	_	0.4	
Off-state collector current	IC(off)	V <sub>F</sub> = 0.7 V, V <sub>CE</sub> = 48 V		_	1	10	μΑ



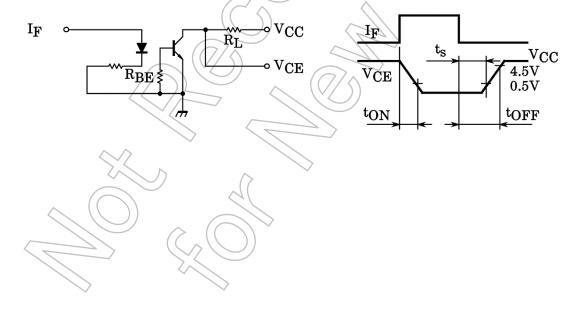
## Isolation Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance (input to output)	Cs	V <sub>S</sub> = 0 V, f = 1 MHz	_	0.8	_	pF
Isolation resistance	Rs	V <sub>S</sub> = 500V, R.H.≤ 60%	5 × 10 <sup>10</sup>	10 <sup>14</sup>	_	Ω
		AC, 60 s	2500	_	_	\/
Isolation voltage	$BV_S$	AC, 1 s, in oil	-((	5000	_	Vrms
		DC, 60 s, in oil		5000	_	Vdc

### Switching Characteristics (Ta = 25°C)

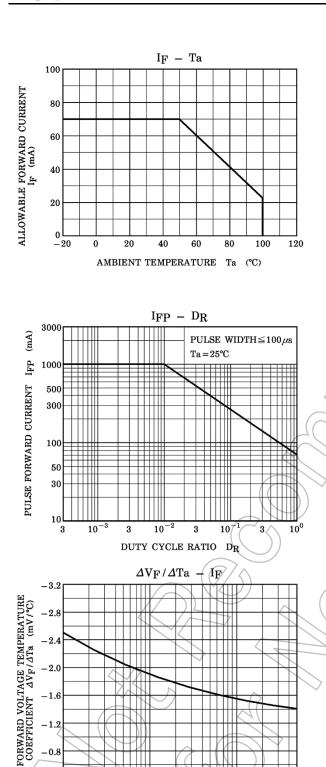
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Rise time	t <sub>r</sub>	4()	_	2	1	
Fall time	tf	V <sub>CC</sub> = 10 V, I <sub>C</sub> = 2 mA	- /	23/	_	
Turn-on time	ton	R <sub>L</sub> = 100 Ω	, –((	3	<u> </u>	μs
Turn-off time	toff		(	3/	/ –	
Turn-on time	ton	$R_L = 1.9 \text{ k}\Omega$ (Fig.1)	7-	2	_	
Storage time	ts	RBE = open	<del>/</del> -))	15	_	μs
Turn-off time	toff	V <sub>C</sub> C = 5V, I <sub>F</sub> = 16mA	$\sim$	25	_	
Turn-on time	ton	$R_L = 1.9 \text{ k}\Omega$ (Fig.1)	)) —	2	_	
Storage time	ts	$R_{BE} = 220 \text{ k}\Omega \text{ (TLP531)}$	_	12	_	μs
Turn-off time	toff	V <sub>CC</sub> = 5V, I <sub>F</sub> = 16mA	_	20	_	

Fig. 1 Switching time test circuit



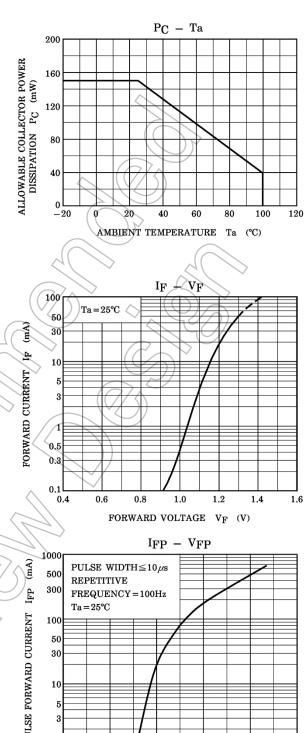
-1.2

-0.4 0.1



30

FORWARD CURRENT IF (mA)



Ta = 25°C

1.2

1.4

30mA

20mA

10mA

5mA

 $I_F=2mA$ 

Ta = 25°C

 $V_{CB} = 0V$ 

 $V_{CB} = 5V$ 

30

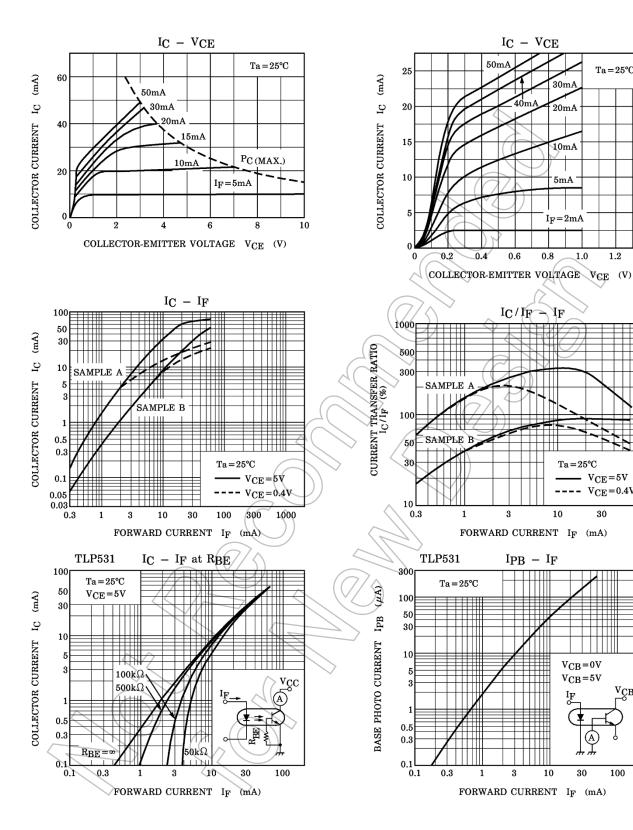
100

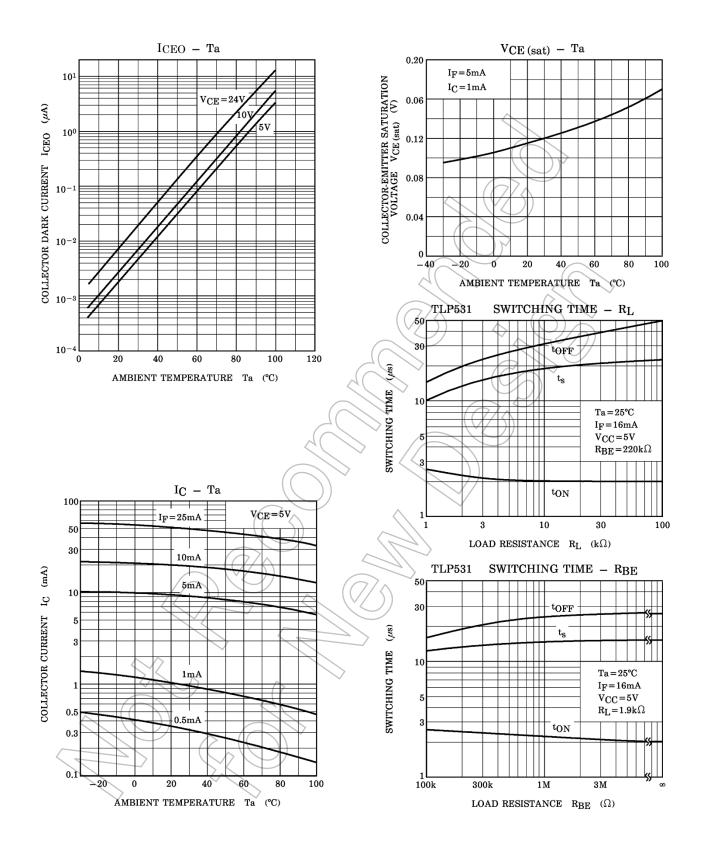
300

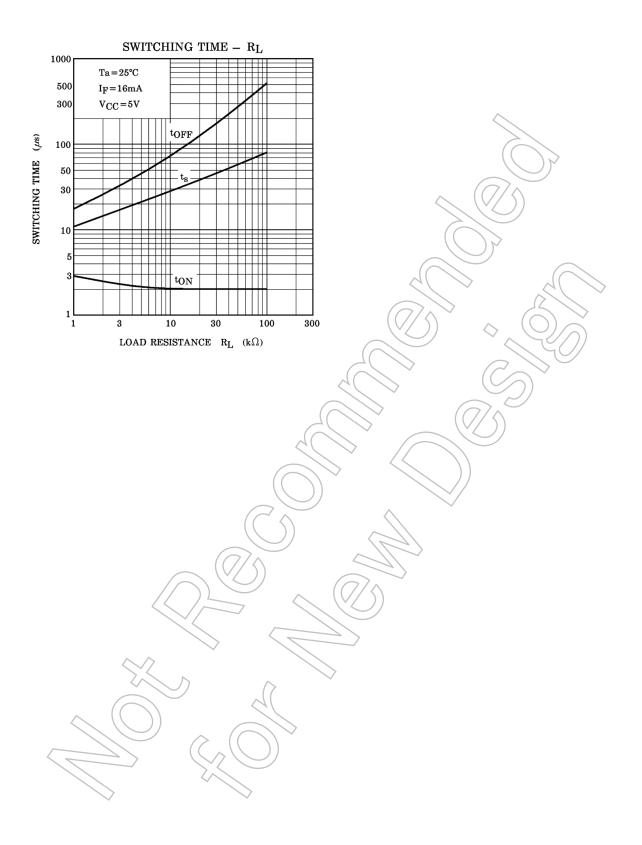
 $V_{\rm CE} = 5V$  $V_{\rm CE}\!=\!0.4V$ 

100

0.8







9 2017-04-17

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